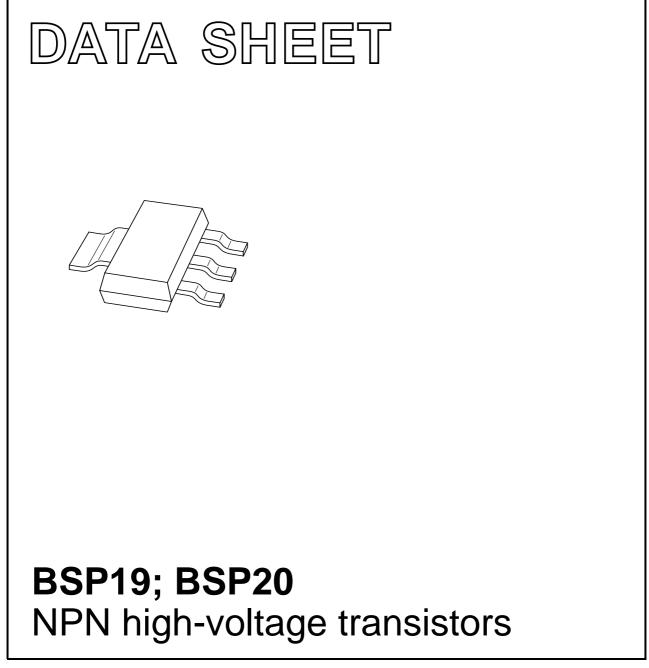
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1997 Mar 03 1999 Jun 01



FEATURES

- Low current (max. 100 mA)
- High voltage (max. 350 V).

APPLICATIONS

- Switching and amplification
- Especially used in telephony and automotive applications.

DESCRIPTION

NPN transistor in a SOT223 plastic package. PNP complement: BSP16.

PINNING

PIN	DESCRIPTION	
1	base	
2, 4	collector	
3	emitter	

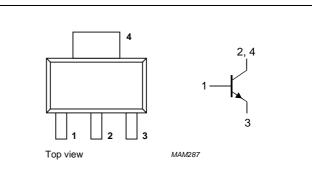


Fig.1 Simplified outline (SOT223) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BSP19		_	400	V
	BSP20		_	300	V
V _{CEO}	collector-emitter voltage	open base			
	BSP19		_	350	V
	BSP20		_	250	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		_	100	mA
I _B	base current (DC)		_	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	_	1.2	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Device mounted on printed-circuit board, single sided copper, tinplated, mounting pad for collector 1 cm². For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

BSP19; BSP20

BSP19; BSP20

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th j-a}	thermal resistance from junction to ambient	note 1	104	K/W	
R _{th j-s}	thermal resistance from junction to soldering point		23	K/W	

Note

1. Device mounted on printed-circuit board, single sided copper, tinplated, mounting pad for collector 1 cm². For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

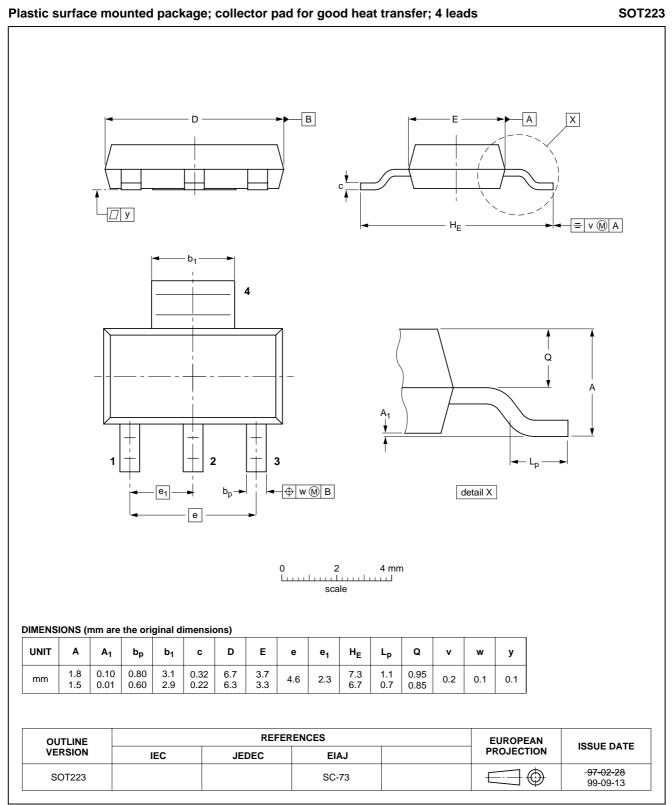
CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CE} = 300 V	-	20	nA
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	_	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V; I _C = 20 mA	40	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 50 mA; I _B = 4 mA	-	0.5	V
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 10 V; f = 1 MHz$	-	2.5	pF
f _T	transition frequency	$V_{CE} = 10 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz}$	70	-	MHz

BSP19; BSP20

PACKAGE OUTLINE



BSP19; BSP20

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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